
HZM27WA

Silicon Epitaxial Planar Zener Diode for Surge Absorb

HITACHI

ADE-208-352A(Z)
Rev 1
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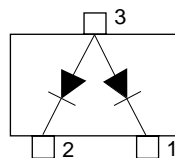
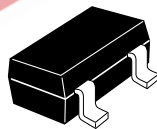
Features

- HZM27WA has two devices, and can absorb external + and -surge.
- MPAK Package is suitable for high density surface mounting and high speed assembly.

Ordering Information

Type No.	Laser Mark	Package Code
HZM27WA	27A	MPAK

Outline



(Top View)

- 1 Cathode
- 2 Cathode
- 3 Anode

HZM27WA

Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Value	Unit
Power dissipation	Pd ¹	200	mW
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

Note 1. Two device total, See Fig.2.

Electrical Characteristics (Ta = 25°C) ^{*1}

Item	Symbol	Min	Typ	Max	Unit	Test Condition
Zener voltage	V _z	25.10	—	28.90	V	I _z = 2 mA, 40ms pulse
Reverse current	I _R	—	—	2	μA	V _R = 21V
Capacitance ^{*2}	C	—	(27)	—	pF	V _R = 0V, f = 1 MHz
Dynamic resistance	r _d	—	—	70	Ω	I _z = 2 mA
ESD-Capability ^{*3}	—	30	—	—	kV	C = 150pF, R = 330 Ω, Both forward and reverse direction 10 pulse

- Notes
1. Per one device.
 2. Reference only.
 3. Failure criterion ; I_R ≤ 2 μA at V_R = 21V.

Main Characteristic

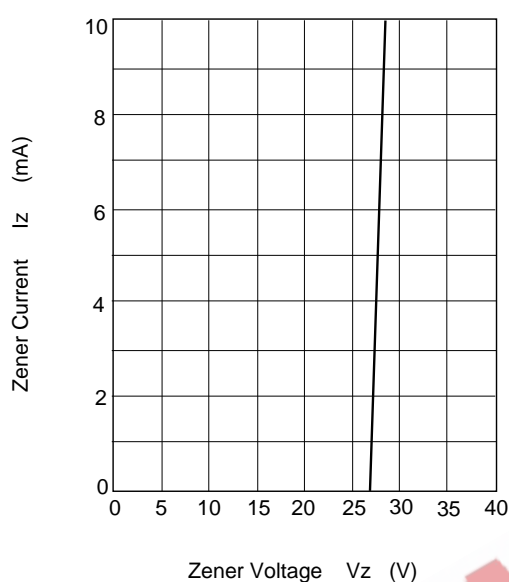


Fig.1 Zener current Vs. Zener voltage

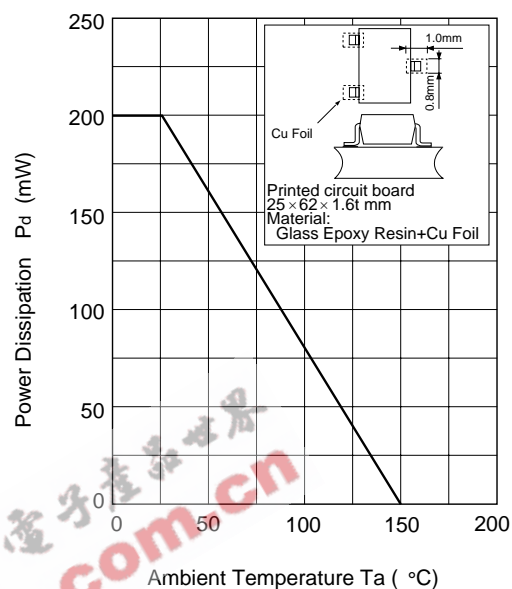


Fig.2 Power Dissipation Vs. Ambient Temperature

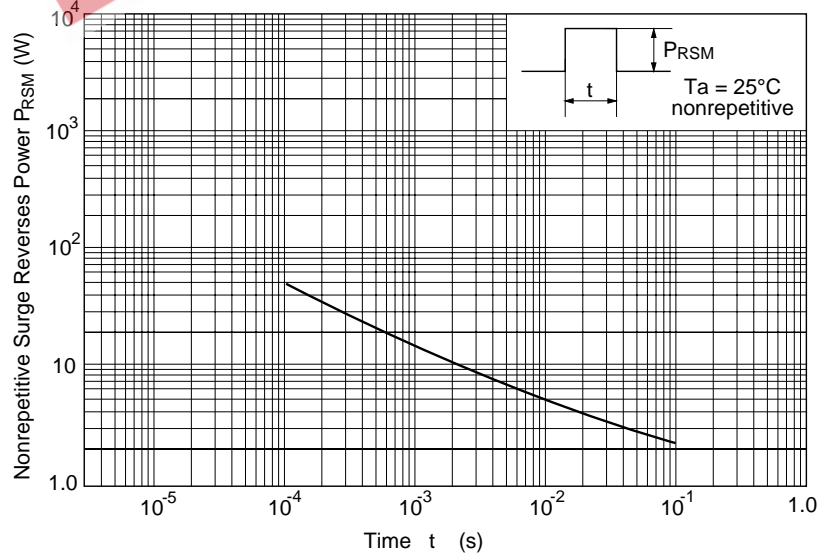


Fig.3 Surge Reverse Power Ratings

HZM27WA

Main Characteristic

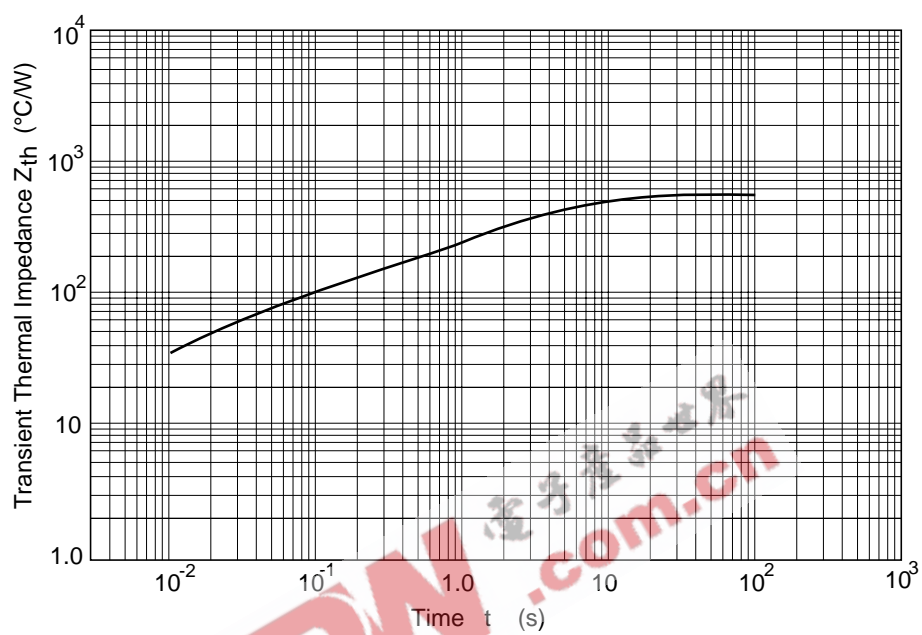
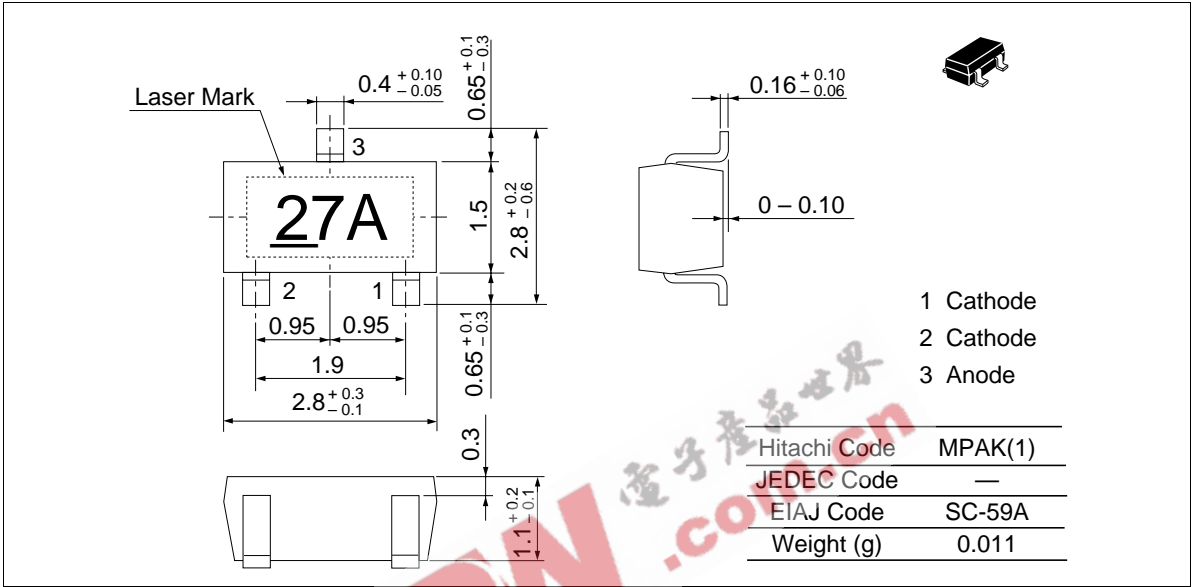


Fig.4 Transient Thermal Impedance

Package Dimensions

Unit : mm



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